

## SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

# N-Channel Junction Silicon FET

## **EC3A04B**—Low-Frequency General-Purpose Amplifier, **Impedance Converter Applications**

### Applicatins

· Low-frequency general-purpose amplifier, impedance conversion, infrared sensor applications.

## Features

- · Small IGSS
- · Small Ciss.
- · Ultraminiature package facilitates miniaturization in end products.
- Halogen free compliance (UL94HB).

## **Specifications**

#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSX		30	V
Gate-to-Drain Voltage	VGDS		-30	V
Gate Current	IG		10	mA
Drain Current	ID		10	mA
Allowable Power Dissipation	PD		100	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Lloit
			min	typ	max	Unit
Gate-to-Drain Breakdown Voltage	V(BR)GDS	IG=-10μΑ, VDS=0V	-30			V
Gate-to-Source Leakage Current	IGSS	V <sub>GS</sub> =-20V, V <sub>DS</sub> =0V			-1.0	nA
Cutoff Voltage	V <sub>GS</sub> (off)	V <sub>DS</sub> =10V, I <sub>D</sub> =1μA	-0.18	-0.65	-2.2	V
Marking : KC				C	ontinued or	next page

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Parameter	Symbol	Conditions	Ratings			Lloit
			min	typ	max	
Drain Current	IDSS	VDS=10V, VGS=0V	0.6*		3.0*	mA
Forward Transfer Admittance	yfs	V <sub>DS</sub> =10V, V <sub>GS</sub> =0V, f=1kHz	3.0	5.0		mS
Input Capacitance	Ciss	V <sub>DS</sub> =10V, V <sub>GS</sub> =0V, f=1MHz		4		pF
Reverse Transfer Capacitance	Crss	VDS=10V, VGS=0V, f=1MHz		1.1		pF
Static Drain-to-Source On-State Resistance	R <sub>DS</sub> (on)	V <sub>DS</sub> =10mV, V <sub>GS</sub> =0V		200		Ω

\* : The EC3A04B is classified by IDSS as follows : (unit : mA).

Rank	2	3
IDSS	0.6 to 1.5	1.2 to 3.0

#### **Package Dimensions**



### Type No. Indication (Top view)



#### Electrical Connection (Top view)







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